Diode Semiconductor Device - Page 1 of 1



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Inclosure Material:
Glass
Overall Length:
Between 0.120 inches and 0.200 inches
Terminal Length:
0.500 inches
Overall Diameter:
Between 0.060 inches and 0.090 inches
Joint Electronic Device Engineering Council/jedec/case Outline Designation:
Do-35
Mounting Method:
Terminal
Features Provided:
Hermetically sealed case
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
40.0 repetitive peak reverse voltage and 40.0 reverse voltage, peak
Current Rating Per Characteristic:
200.00 milliamperes forward current, average absolute and 15.00 amperes forward current, average preset
Power Rating Per Characteristic:
400.0 milliwatts small-signal input power, common-collector absolute
Maximum Operating Tempurature Per Measurement Point:
125.0 degrees celsius junction
Terminal Type And Quantity:
2 uninsulated wire lead
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
No
Fiig:
A110a0